

## 600V N-Channel Super Junction MOSFET

Voltage	600 V	R <sub>dson</sub>	74 mΩ
Current	53 A	Q <sub>g</sub>	84 nC

### Feature:

- R<sub>DSON</sub> Max, V<sub>GS</sub>@10V: 74mΩ
- Fast recovery Qrr /Trr performance.
- High Speed Switching and Low R<sub>DSON</sub>
- 100% Avalanche Tested
- 100% R<sub>g</sub> Tested
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case: TO-247AD-4L package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 6.9524 grams

### Application

- Server Power / Telecom power / Industrial Power / EV Charging Station.

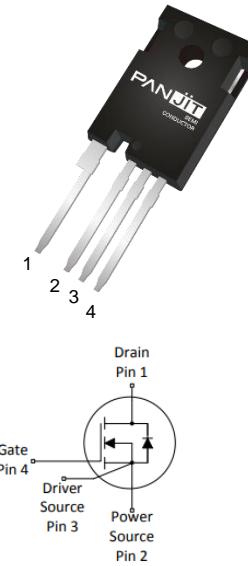
### Absolute Maximum Ratings (T<sub>A</sub> = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage @ T <sub>jmax</sub>	V <sub>DS</sub>	650	V
Drain-Source Voltage	V <sub>DS</sub>	600	
Gate-Source Voltage	V <sub>GS</sub>	±30	A
Continuous Drain Current	I <sub>D</sub>	53	
		33	
Pulsed Drain Current	I <sub>DM</sub>	117	A
Single Pulse Avalanche Energy <sup>(Note 6)</sup>	E <sub>AS</sub>	1750	mJ
MOSFET dv/dt ruggedness <sup>(Note 7)</sup>	dv/dt	120	V/ns
Reverse diode dv/dt <sup>(Note 8)</sup>	dv/dt	100	V/ns
Maximum diode commutation speed	di <sub>F</sub> /dt	1200	A/μs
Power Dissipation	P <sub>D</sub>	446	W
		178	
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55~150	°C

### Thermal Characteristics

PARAMETER	SYMBOL	MAXIMUM	UNITS
Thermal Resistance	Junction-to-Case	R <sub>θJC</sub>	0.3
	Junction-to-Ambient <sup>(Note 3)</sup>	R <sub>θJA</sub>	50

**TO-247AD-4L**



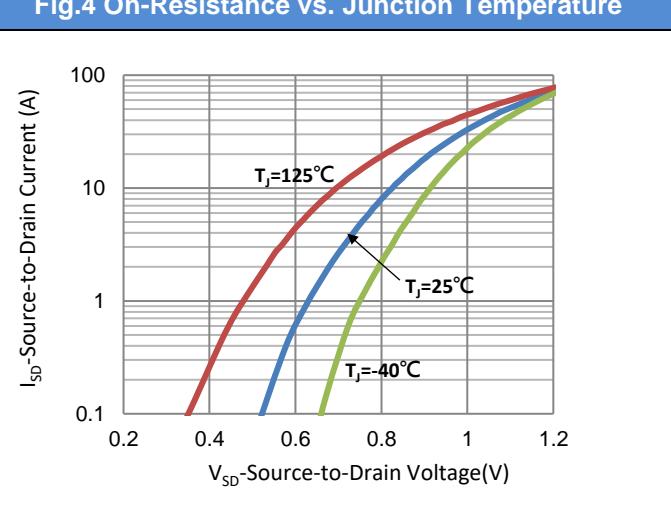
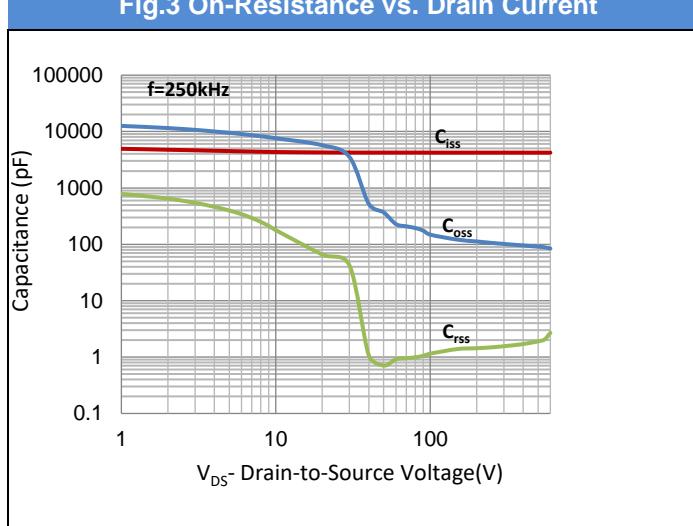
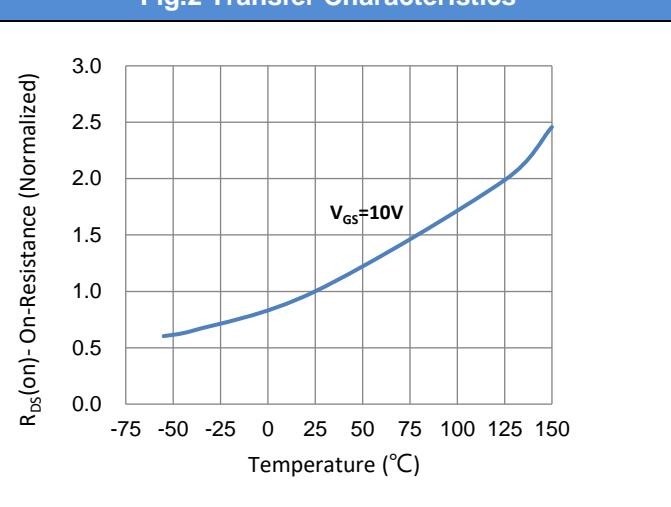
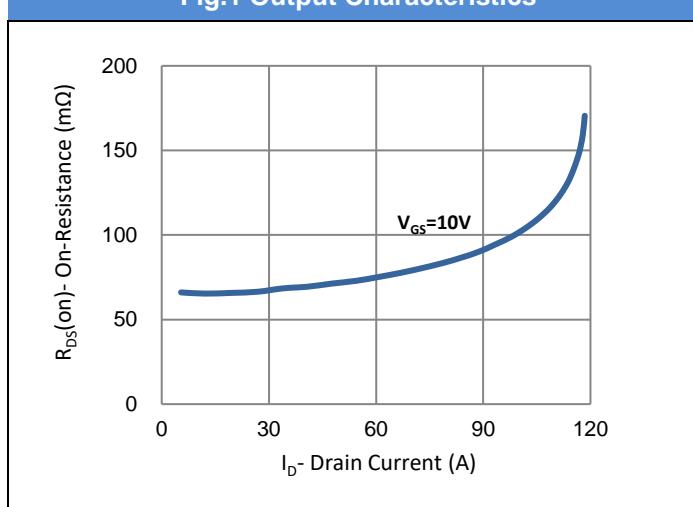
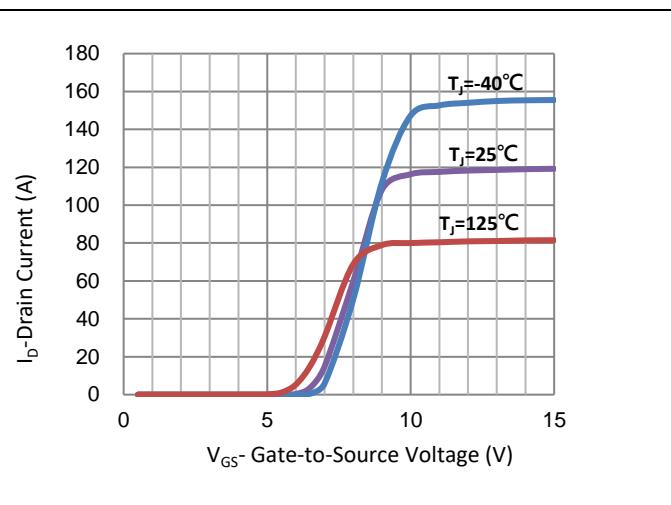
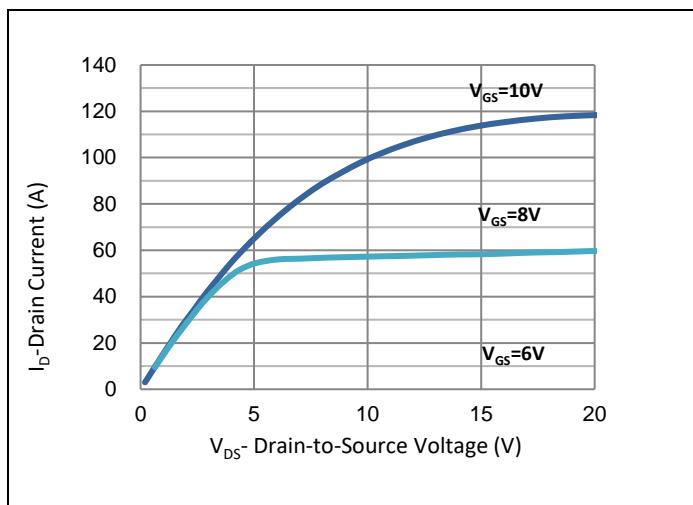
**Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=1\text{mA}$	600	-	-	V
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	4.3	4.8	5.8	
Drain-Source On-State Resistance	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=26.5\text{A}$ <sup>(Note 1)</sup>	-	63	74	$\text{m}\Omega$
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}}=600\text{V}, V_{\text{GS}}=0\text{V}$	-	-	10	$\mu\text{A}$
Gate-Source Leakage Current	$I_{\text{GSS}}$	$V_{\text{GS}}=\pm 30\text{V}, V_{\text{DS}}=0\text{V}$	-	-	$\pm 100$	nA
Transfer characteristics	$g_{\text{fs}}$	$V_{\text{DS}}=20\text{V}, I_{\text{D}}=26.5\text{A}$	-	27	-	S
<b>Dynamic</b> (Note 5)						
Total Gate Charge	$Q_g$	$V_{\text{DS}}=480\text{V}, I_{\text{D}}=26.5\text{A}, V_{\text{GS}}=10\text{V}$	-	84	-	nC
Gate-Source Charge	$Q_{\text{gs}}$		-	31	-	
Gate-Drain Charge	$Q_{\text{gd}}$		-	34	-	
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=400\text{V}, V_{\text{GS}}=0\text{V}, f=250\text{kHz}$	-	4228	-	pF
Output Capacitance	$C_{\text{oss}}$		-	95	-	
Reverse Transfer Capacitance	$C_{\text{rss}}$		-	1.7	-	
Effective Output Capacitance Energy Related	$C_{\text{o(er)}}$	$V_{\text{DS}}=0\text{V}$ to $400\text{V}$ , $V_{\text{GS}}=0\text{V}, f=250\text{kHz}$ (Note 4)	-	137	-	
Turn-On Delay Time	$t_{\text{d(on)}}$	$V_{\text{DD}}=300\text{V}, I_{\text{D}}=26.5\text{A}, V_{\text{GS}}=10\text{V}, R_{\text{G}}=25\Omega$ (Note 2)	-	177	-	ns
Turn-On Rise Time	$t_r$		-	177	-	
Turn-Off Delay Time	$t_{\text{d(off)}}$		-	260	-	
Turn-Off Fall Time	$t_f$		-	107	-	
Gate Resistance	$R_g$	$f=1.0\text{MHz}$	-	20	-	$\Omega$
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_s$		-	-	53	A
Diode Forward Voltage	$V_{\text{SD}}$	$I_s=26.5\text{A}, V_{\text{GS}}=0\text{V}$	-	0.9	1.5	V
Reverse Recovery Charge	$Q_{\text{rr}}$	$I_s=26.5\text{A}$ $dI/dt=100\text{A}/\mu\text{s}$	-	1.08	-	$\mu\text{C}$
Reverse Recovery Time	$T_{\text{rr}}$		-	155	-	ns

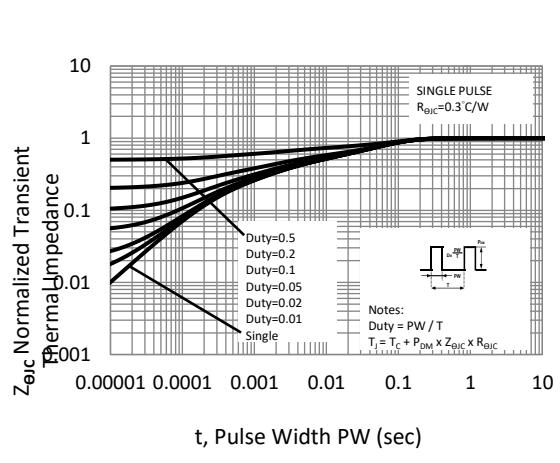
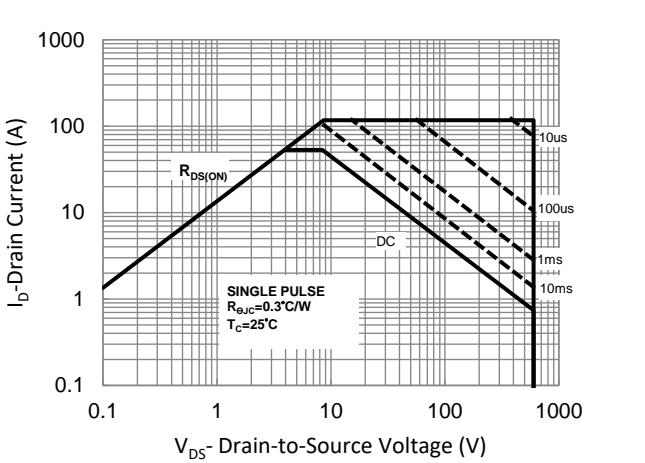
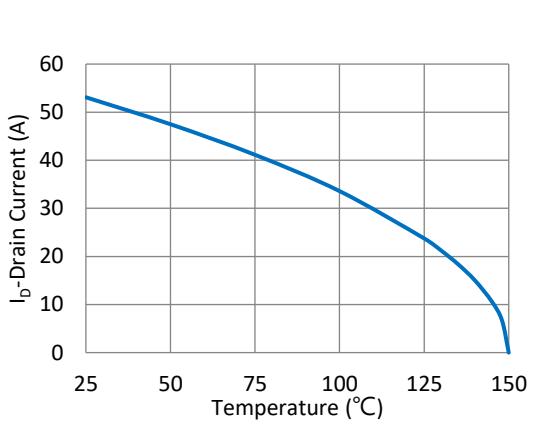
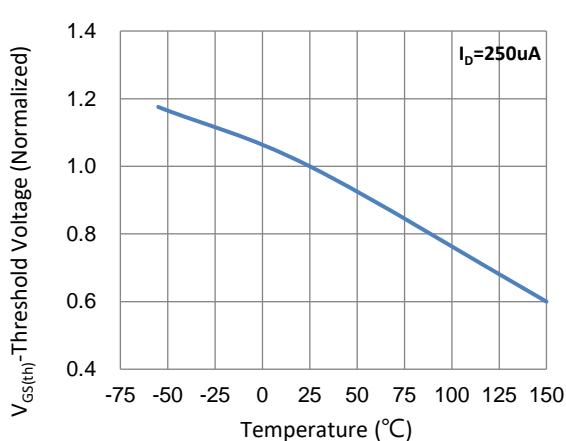
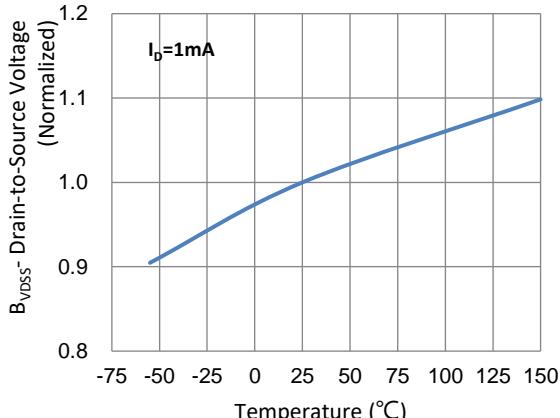
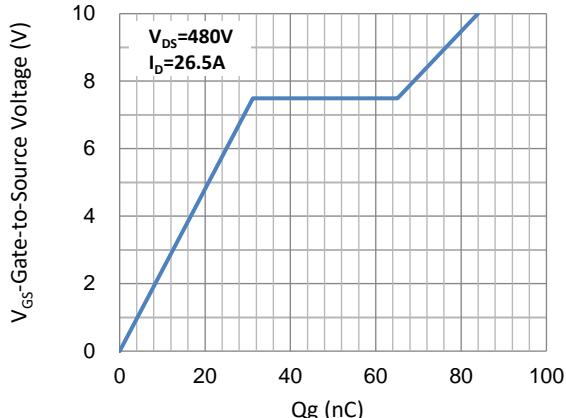
**NOTES :**

1. Pulse width  $\leq 300\mu\text{s}$ , Duty cycle  $\leq 2\%$ .
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\thetaJA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance.
4.  $C_{\text{o(er)}}$  is a capacitance that gives the same stored energy as  $C_{\text{oss}}$  while  $V_{\text{DS}}$  is rising from 0V to 80%  $V_{(\text{BR})\text{DSS}}$ .
5. Guaranteed by design, not subject to production testing.
6.  $E_{\text{AS}}$  is calculated based on the condition of  $I_{\text{D}}=6.7\text{A}; V_{\text{DD}}=50\text{V}; L=80\text{mH}$ .
7.  $V_{\text{DS}}=0\ldots 400\text{V}$ .
8.  $V_{\text{DS}}=0\ldots 400\text{V}, I_{\text{SD}}=26.5\text{A}$ .

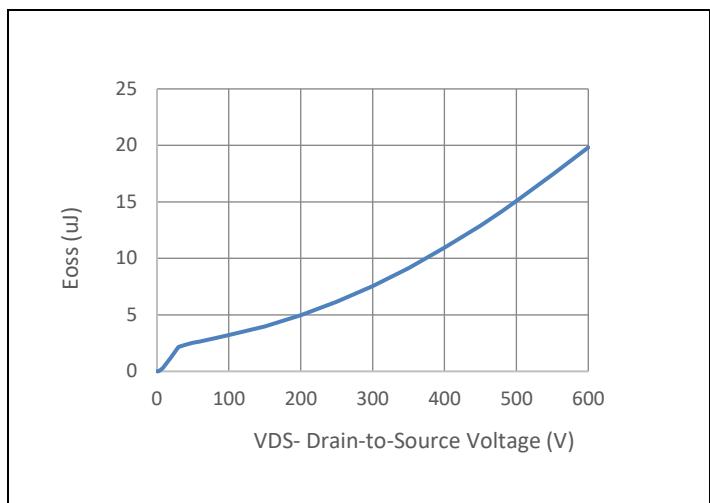
**TYPICAL CHARACTERISTIC CURVES**



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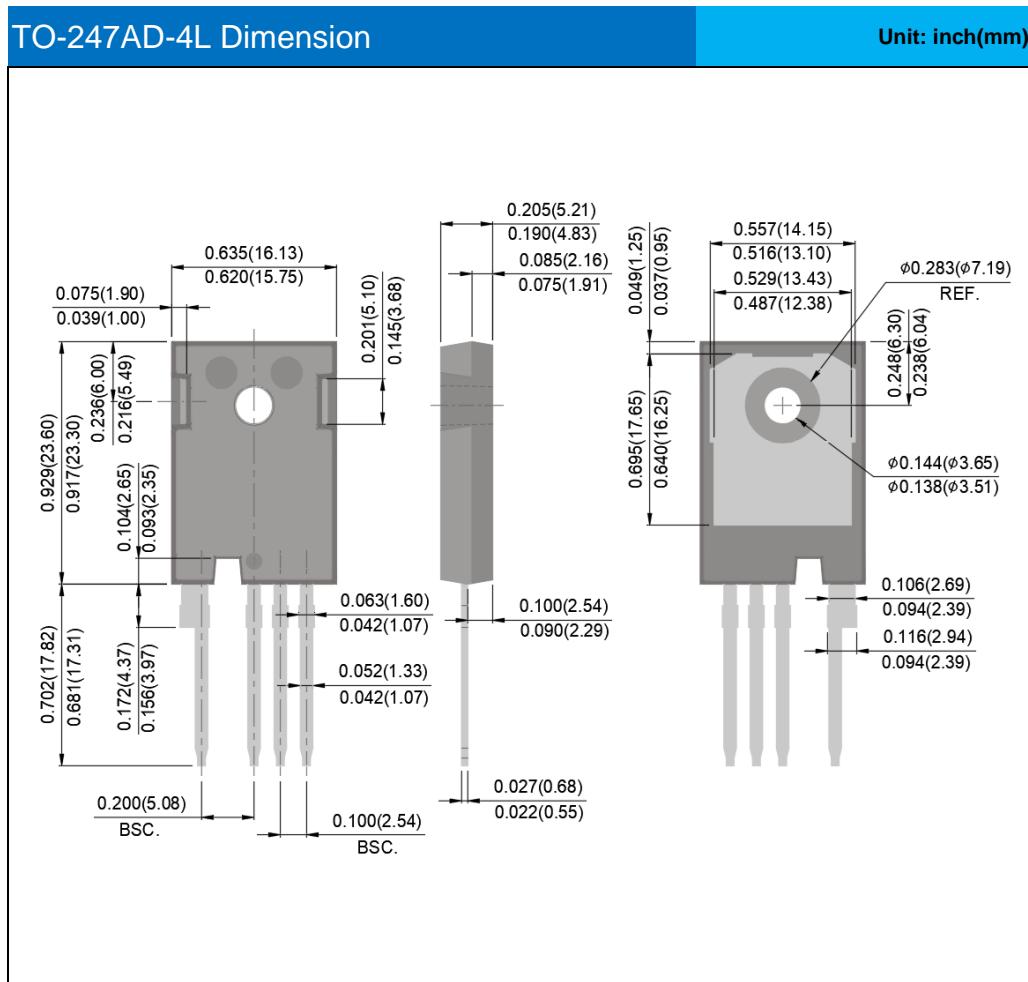


**Fig.13 Typ. Coss Stored Energy**

## Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJMK074N60FRCH	TO-247AD-4L	30pcs / Tube	074N60FRCH

## Packaging Information



## Marking Diagram

PJ	= Year Code
074N60FRCH	
YWLL x	

**Y** = Year Code  
**W** = Week Code (A~Z)  
**LL** = Lot Code (00~99)  
**x** = Production Line Code

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